

TMO-M50S



Holdover up to 1.5 μ s / 24 hours

Features

- Applications: Base station, Clock Reference, 5G
- High frequency stability vs. temperature ($\leq \pm 5 \times 10^{-11}$)

Parameter	Specification			
	TMO-M50S5		TMO-M50S12	
Frequency Range	10.000 MHz			
Standard Frequency	10.000 MHz			
Frequency Accuracy	1×10^{-12}			
Supply Voltage [Vdc]	Code		Vdc	
	5		5.0 V \pm 5%	
	12		12.0 V \pm 5%	
Current Consumption [Idc]	5 Vdc		12 Vdc	
Warm up current	< 1500 mA		< 600 mA	
Steady state current @25°C	< 700 mA		< 300 mA	
Frequency Stability	Code	OTR	°C	Code
vs Operating Temperature Range [OTR]	EK	0 to +70		50p
	JK	-20 to +70		n10
				n20
				$\leq \pm 20 \times 10^{-11}$
Holdover Capability	Code		Holdover	
$\Delta T = \pm 2^\circ\text{C}$, after 7days turn ON	R		1.0 μ s / 8 hours	
	S		2.0 μ s / 8 hours	
	T		1.5 μ s / 24 hours	
GNSS Receiver	Code		GNSS receiver	
GPS, Beidou, GLONASS, Galileo	U		Included	
	V		Without	
G-sensitivity	Code		G-sens per axis	
Standard	Blank		< 3ppb/g	
Low-Gsens	G		< 1.5ppb/g	

Ordering Guide: TMO-M50S5-EKn10-T-U-G 10MHz

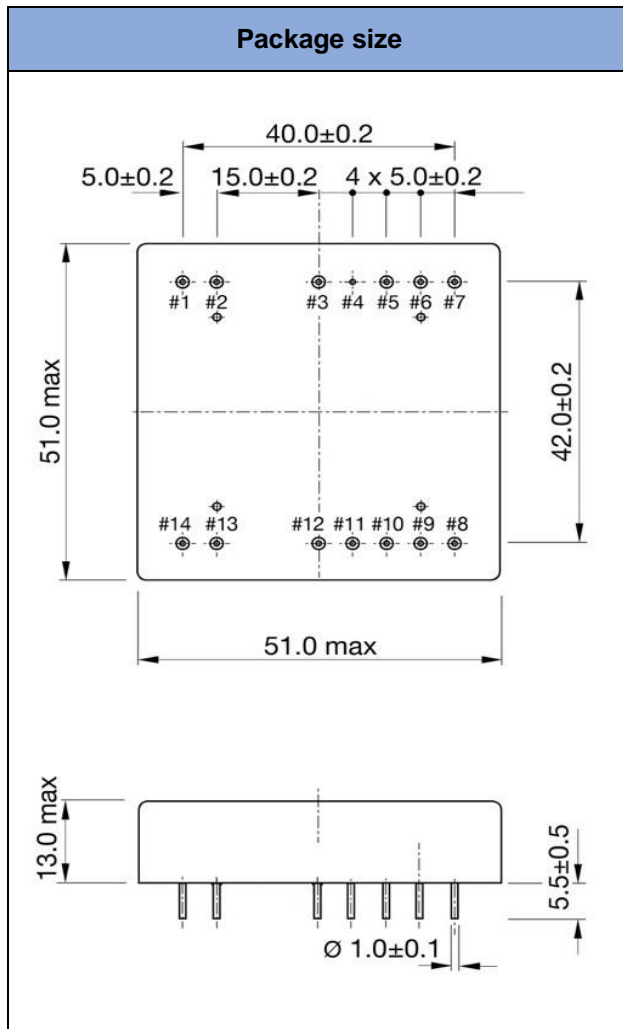
RF Output Signal	Sine wave	
Output Level	5 \pm 2dBm / Load 50 Ω	
Harmonics & Spurious	-30dBc / -70dBc	
Phase Noise @ 25°C	Typical value [static conditions]	
10 MHz carrier frequency	10 Hz	≤ -115 dBc/Hz
	100 Hz	≤ -135 dBc/Hz
Lower Phase Noise possible with Vdc 12V	1 kHz	≤ -145 dBc/Hz
	10 kHz	≤ -147 dBc/Hz
	100 kHz	≤ -150 dBc/Hz
Short Term Stability [Allan Variance]	$\leq 1 \times 10^{-11}$ @ 1s	
1pps Output Signal	LVC MOS	
Output Level	$V_{OH} > 2.4$ V $V_{OL} < 0.5$ V	
Pulse width	10 ms	
1pps Input Reference	LVC MOS	
Output Level	$V_{OH} > 2.4$ V $V_{OL} < 0.5$ V	
State Input Lock	> 2.4 V @ < 5 mA Load	
State Holdover	< 0.5 V @ < 5 mA Load	
Lock Status Indicator		
Module Locked	> 2.4 V @ < 5 mA Load	
Module Holdover	< 0.5 V @ < 5 mA Load	

Note 1: unless otherwise specified conditions are @ 25°C still air

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Environmental test	
vibration	acceleration: 5 g; 10 Hz up to 200 Hz and down to 10 Hz; all 3 axes
shock	75 g, half-sine, 3 ms



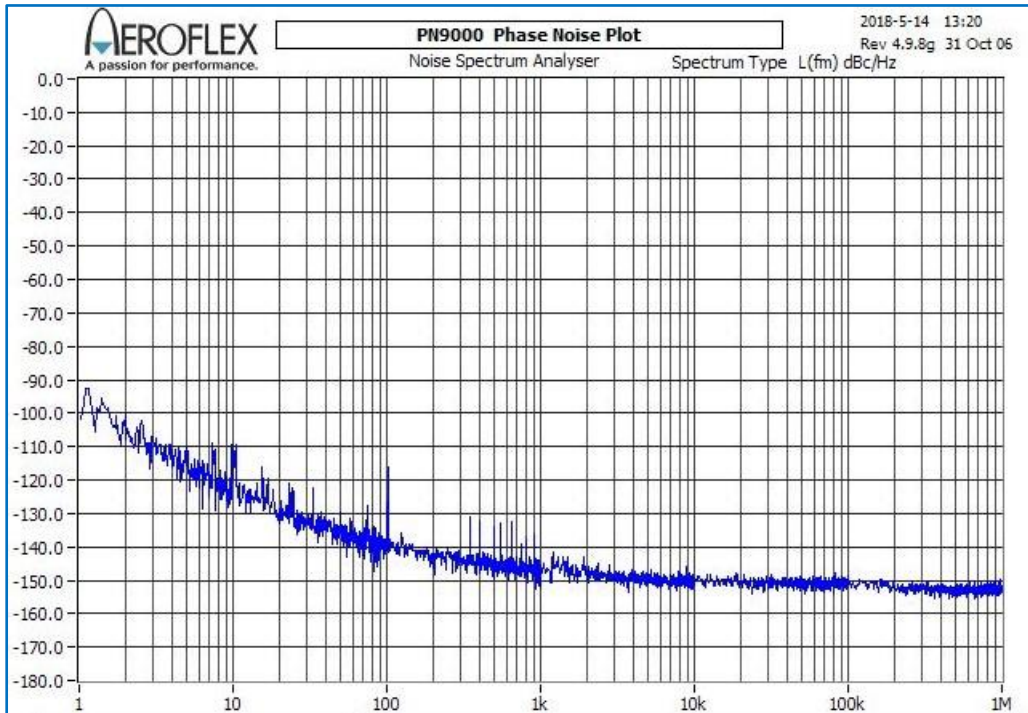
Pin#	Pin Function
1	NC
2	NC
3	Vdc
4	GND
5	LOCK OUTPUT
6	NC
7	TX OUTPUT
8	STATE INPUT
9	NC
10	1pps INPUT
11	GND
12	1pps OUTPUT
13	GND
14	10 MHz OUTPUT

MARKING



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Phase Noise



Holdover 24 hours

